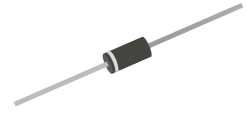


SR520-G Thru. SR5200-G

Forward current: 5.0A

Reverse voltage: 20 to 200V

RoHS Device

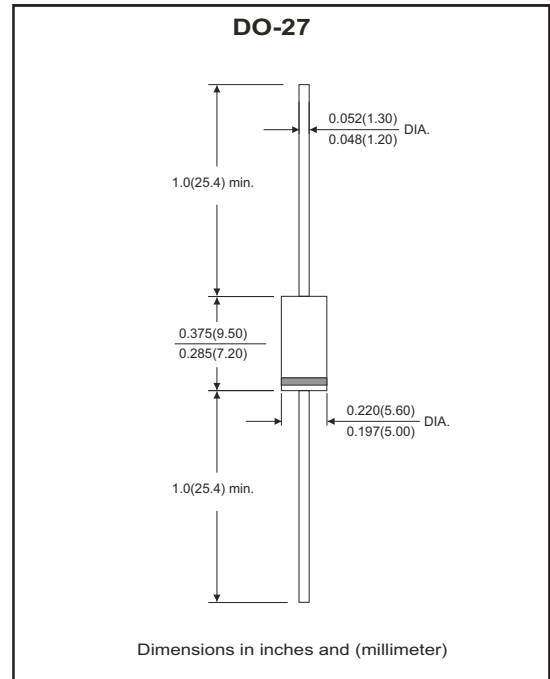


Features

- Axial lead type devices for through hole design.
- Low power loss, high efficiency.
- High current capability, Low forward voltage drop.
- High surge capability.
- Guardring for overvoltage protection.
- Ultra high-speed switching.
- Silicon epitaxial planar chip, metal silicon junction.
- Lead-free part meets environmental standards of MIL-STD-19500/228

Mechanical Data

- Case: Molded plastic, DO-201AD/DO-27
- Epoxy: UL94V-0 rate flame retardant.
- Lead: Axial lead, solderable per MIL-STD-202, Method 208 guaranteed.
- Polarity: color band denoted cathode end.
- Weight: 1.10 gram (approx.).



Maximum Ratings and Electrical Characteristics

Ratings at Ta=25°C unless otherwise noted.
Single phase, half wave, 60Hz, resistive or inductive loaded.
For capacitive load, derate current by 20% .

Parameter	Symbol	SR520 -G	SR540 -G	SR560 -G	SR5100 -G	SR5150 -G	SR5200 -G	Unit
Maximum recurrent peak reverse voltage	V _{RRM}	20	40	60	100	150	200	V
Maximum RMS voltage	V _{RMS}	14	28	42	70	105	140	V
Maximum DC blocking voltage	V _{DC}	20	40	60	100	150	200	V
Maximum instantaneous forward voltage at I _F =5A, T _A =25°C	V _F	0.50	0.55	0.75	0.81	0.87	0.90	V
Operating junction temperature range	T _J	-50 ~ +150				-50 ~ +175		°C

Parameter	Conditions	Symbol	MIN.	TYP.	MAX.	Unit
Forward rectified current	see Fig.1	I _o			5.0	A
Forward surge current	8.3ms single half sine-wave superimposed on rate load (JEDEC method)	I _{FSM}			125	A
Reverse Current	V _R =V _{RRM} T _A =25°C	I _R			0.5	mA
	V _R =V _{RRM} T _A =100°C	I _R			20	mA
Thermal Resistance	Junction to ambient	R _{θJA}		24		°C/W
Diode Junction capacitance	f=1MHz and applied 4V DC reverse Voltage	C _J		380		pF
Storage temperature		T _{STG}	-50		+175	°C

RATING AND CHARACTERISTIC CURVES (SR520-G Thru. SR5200-G)

Fig.1 - Typical Forward Current Derating Curve

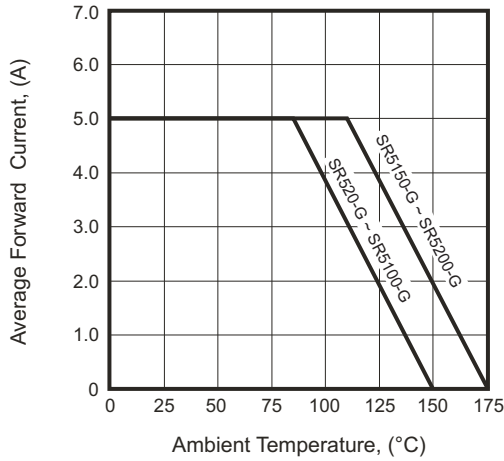


Fig.2 - Typical Forward Characteristics

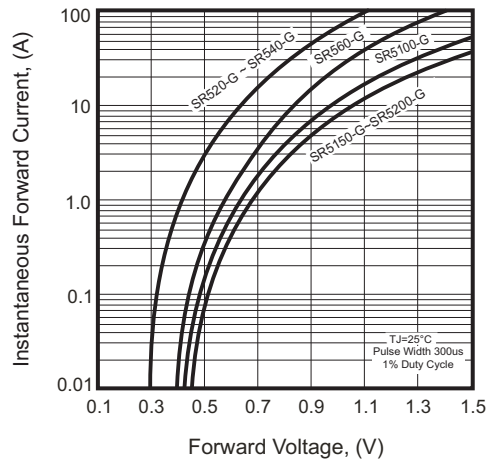


Fig.3 - Maximum Non-repetitive Forward Surge Current

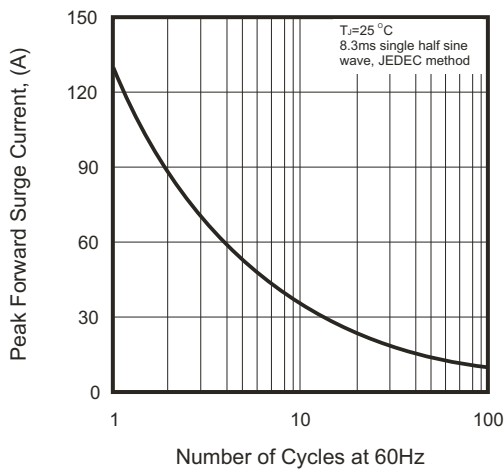


Fig.4 - Typical Junction Capacitance

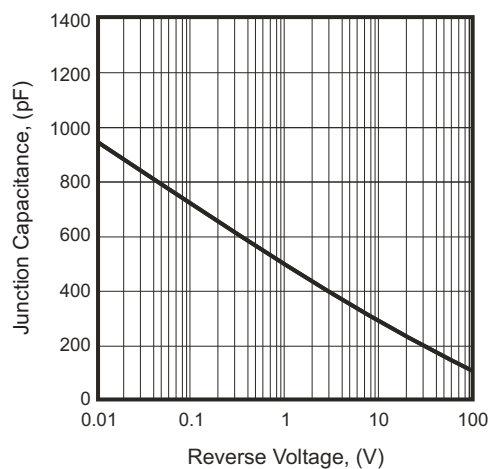
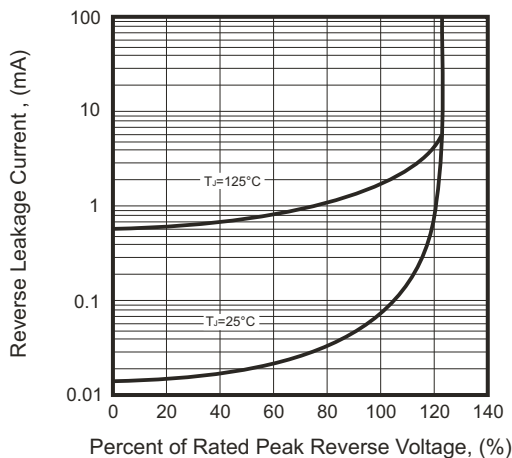
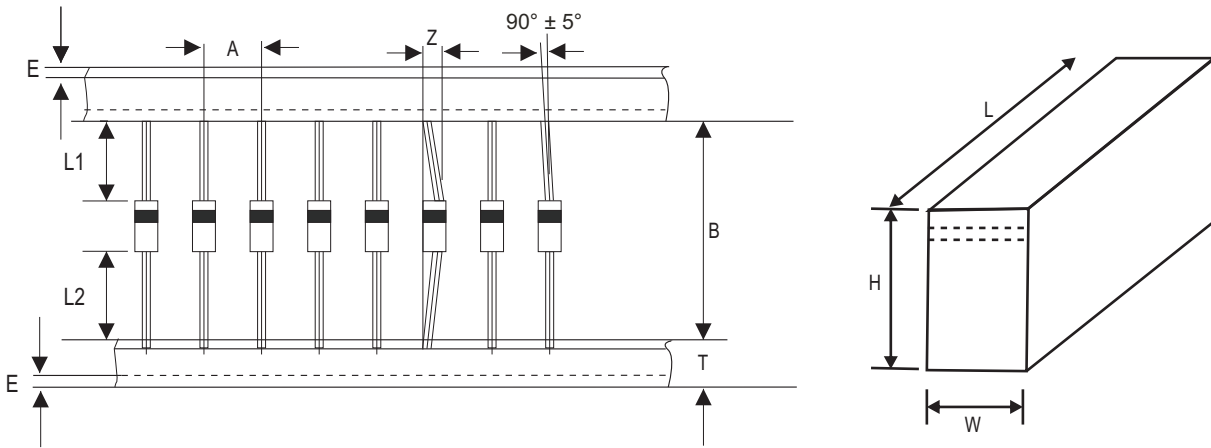


Fig.5 - Typical Reverse Characteristics



Taping Specification For Axial Lead Diodes

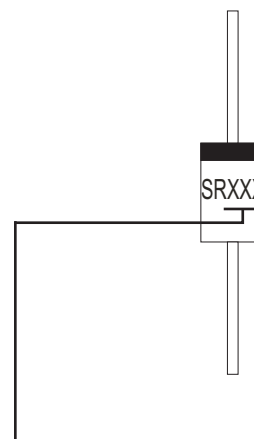


DO-27	SYMBOL	A	B	Z	T	E	L1	L2
	(mm)	9.30 ± 0.50	52.40 (max)	1.20 (max)	6.00 ± 0.40	0.80 (max)	1.00 (max)	1.00 (max)
	(inch)	0.366 ± 0.020	2.063 (max)	0.047 (max)	0.236 ± 0.016	0.031 (max)	0.039 (max)	0.039 (max)

DO-27	SYMBOL	D1	D0	D	W0	L	W	H
	(mm)	85.70 ± 0.30	16.60 ± 0.40	330.00	72.00 ± 3.00	260.00	75.00	145.00
	(inch)	3.374 ± 0.012	0.654 ± 0.016	13.000	2.835 ± 0.118	10.236	2.953	5.709

Marking Code

Part Number	Marking Code
SR520-G	SR52
SR540-G	SR54
SR560-G	SR56
SR5100-G	SR510
SR5150-G	SR515
SR5200-G	SR520



XX / XXX = Product type marking code

Standard Packaging

Case Type	AMMO PACK	
	BOX (pcs)	CARTON (pcs)
DO-27	500	9,000